

Dual channel digital isolator


S08N
S08W

Product status link

[STISO621](#)
[STISO621W](#)

Product label



Features

- Dual channel, digital isolator with 1 – 1 channel directionality
- High data rate up to 100 Mbps
- Wide t_{amb} range operation: - 40°C to 125°C
- High common-mode transient: >50k V/μs
- From 3 V to 5.5 V, supply levels
- 3.3 V and 5 V level translation
- Low-power consumption
- Pulse width distortions < 3 ns
- 6k V galvanic isolation in SO8W package
- SO8 narrow and wide package options
- Safety and regulatory approvals
 - UL1577 certified, file number: E362869
 - IEC 60747-17 certified in SO8W package, File number: 5022192-4880-0002/300335
 - V_{IORM} (Maximum repetitive isolation voltage) up to 1.5k V_{PEAK}
 - V_{IOTM} (Maximum transient isolation voltage) up to 5k V_{PEAK}
 - V_{IOSM} (Maximum surge isolation voltage) up to 6k V_{PEAK}
 - V_{ISO} (Isolation withstand voltage) up to 3.5k V_{RMS}

Applications

- Optocoupler replacement in industrial application
- Industrial field bus isolation
- Battery monitor and motor drive
- Size-critical multichannel isolation

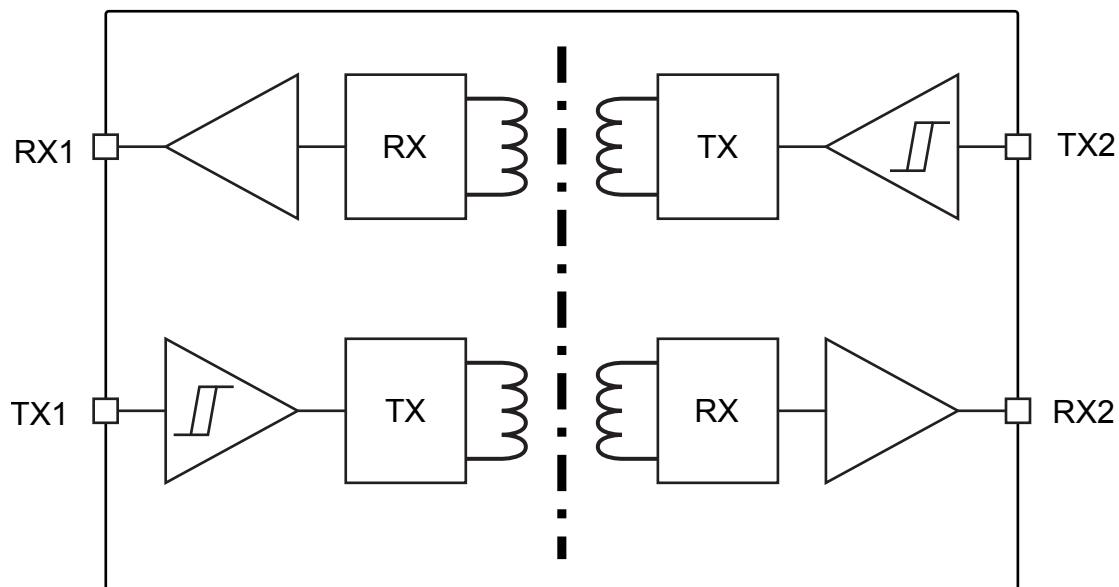
Description

The **STISO621** /**STISO621W** are dual-channel digital isolators based on the ST thick oxide galvanic isolation technology.

The devices provide two independent channels in the opposite direction with Schmitt trigger input, providing robustness to noise and high speed input/output switching time.

1 Block diagram

Figure 1. Block diagram



2 Electrical data

2.1 Absolute maximum ratings

Table 1. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DDX}	Supply voltage (each side)	-0.3 to 7	V
V_{IN}	Logic input voltage	-0.3 to 7	V
I_O	Output current	5	mA
T_j	Junction temperature	-40 to 150	°C

2.2 Electrical sensitivity

Table 2. ESD protection ratings

Symbol	Parameter	Test condition	Class	Value	Unit
HBM	Human Body Model	Conforming to ANSI/ESDA/JEDEC JS-001-2014	H2	+/- 2	kV
CDM	Charge Device Model	All pins Conforming to ANSI/ESDA/JEDEC JS-002-2014	C2B	+/- 750	V
MM	Machine Model	Conforming to EIA/JESD22-A115-C	NC	+/- 200	V

2.3 Recommended operating conditions

Table 3. Recommended operating conditions

Symbol	Parameter	Min	Typ	Max	Unit
V_{DDX}	Supply voltage (each side)	3		5.5	V
V_{IN}	Logic input voltage	0		5	V
T_{amb}	Ambient temperature	-40		125	°C

2.4 Electrical characteristics

Table 4. Electrical characteristics at VDD1 = VDD2 = 5 V

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V _{DDXon}	V _{DDX} on threshold	V _{DDX} rising from 0 V			2.8	V
V _{DDXhyst}	V _{DDX} off hysteresis	V _{DDX} falling from 5 V			0.1	V
IDD _X	Supply current	DC		1.65	2	mA
		10 Mbps, C _L = 20 pF		3.65	5	mA
		100 Mbps, C _L = 20 pF		18	20	mA
V _{IHL}	Low-level Schmitt trigger threshold	Logic input falling Full supply range	0.8			V
V _{ILH}	High-level Schmitt trigger threshold	Logic input rising Full supply range			2	V
V _{IHyst}	Schmitt trigger input hysteresis				0.5	V
V _{OL}	Low-level output voltage	I _{OH} = 4 mA			0.4	V
V _{OH}	High-level output voltage	I _{OL} = 4 mA	V _{DDX} – 0.3			V
Z _O	Output impedance		-40%	50	+40%	Ω
f _{MAX}	Maximum data rate	V _{IH} = 5 V	100			Mbps
t _r	Output rise time	C _L = 15 pF		2	4	ns
t _f	Output fall time	C _L = 15 pF		2	4	ns
t _{DHL}	Propagation delay H to L	See Figure 5		25	42	ns
t _{DLH}	Propagation delay L to H	See Figure 5		25	42	ns
t _{POWUP}	Power-up time				30	μs
t _{REFRESH}	Refresh time ⁽¹⁾			1	2	μs
t _{WD}	Watchdog timeout		2		6	μs
PWD	Pulse width distortion t _{DHL} – t _{DLH}	Full temperature range ⁽²⁾			3	ns
CMTI	Common-mode transient immunity	⁽³⁾	50	65		kV/μs

1. A refresh function ensures the persistence of the transmitted data across the isolation. The state of TX is periodically transmitted every t_{REFRESH}
2. Not tested in production. A characterization on a limited number of samples, representing the worst case of production flow, evaluates the limit.
3. Not tested in production. A characterization on a limited number of samples and simulations, evaluates the limit.

Note: **Testing conditions: Typical values are defined at t_{amb} = 25°C and VDD1 = VDD2 = 5 V, minimum and maximum limits applies to the full temperature range (Tested in production at t_{amb} = 25°C. A characterization on a limited quantity of samples, evaluates the limit in the full temperature range), unless otherwise specified.**

Table 5. Electrical characteristics at VDD1 = VDD2 = 3 V

Symbol	Parameter	Test condition	Min.	Typ.	Max.	Unit
V _{DDXon}	V _{DDX} on threshold	V _{DDX} rising from 0 V			2.8	V
V _{DDXhyst}	V _{DDX} off hysteresis	V _{DDX} falling from 5 V			0.1	V
I _{DDX}	Supply current	DC		1.5	2	mA
		10 Mbps, C _L = 20 pF		3	5	mA
		100 Mbps, C _L = 20 pF		11	20	mA
V _{IHL}	Low-level Schmitt trigger threshold	Logic input falling Full supply range	0.8			V
V _{ILH}	High-level Schmitt trigger threshold	Logic input rising Full supply range			2	V
V _{IHyst}	Schmitt trigger input hysteresis				0.5	V
V _{OL}	Low-level output voltage	I _{OH} = 4 mA			0.4	V
V _{OH}	High-level output voltage	I _{OL} = 4 mA	V _{DDX} – 0.3			V
Z _O	Output impedance		-40%	50	+40%	Ω
f _{MAX}	Maximum data rate	V _{IH} = 3.3 V	100			Mbps
t _r	Output rise time	C _L = 15 pF		1.5	4	ns
t _f	Output fall time	C _L = 15 pF		1.5	4	ns
t _{DHL}	Propagation delay H to L	See Figure 5		25	42	ns
t _{DLH}	Propagation delay L to H	See Figure 5		25	42	ns
t _{POWUP}	Power-up time				30	μs
t _{REFRESH}	Refresh time ⁽¹⁾			1	2	μs
t _{WD}	Watchdog timeout		2		6	μs
PWD	Pulse width distortion t _{DHL} – t _{DLH}	Full temperature range ⁽²⁾			3	ns
CMTI	Common-mode transient immunity	⁽³⁾	50	65		kV/μs

1. A refresh function ensures the persistence of the transmitted data across the isolation. The state of TX is periodically transmitted every t_{REFRESH}
2. Not tested in production. A characterization on a limited number of samples, representing the worst case of production flow, evaluates the limit
3. Not tested in production. A characterization on a limited number of samples and simulations, evaluates the limit.

Note: **Testing conditions: Typical values are defined at t_{amb} = 25°C and VDD1 = VDD2 = 3 V, minimum and maximum limits applies to the full temperature range (Tested in production at t_{amb} = 25°C. A characterization on a limited quantity of samples, evaluates the limit in the full temperature range), unless otherwise specified.**

3 Thermal data

Table 6. Thermal data

Symbol	Parameter	Max. value	Unit
$R_{th\ j-amb}$	Thermal resistance, junction to ambient ⁽¹⁾	97 ⁽²⁾	°C/W
$R_{th\ jc-top}$	Thermal resistance, junction to top case ⁽³⁾	47	°C/W

1. As per JESD51-7

2. Maximum power dissipation = 670mW (@ $T_{amb} = 85^{\circ}C$, $T_J < 150^{\circ}C$)

3. As per JESD51-3

4 Isolation characteristics

Table 7. Isolation and safety specification (SO8N package)

Symbol	Parameter	Test conditions	Value	Unit
General				
CLR	Clearance (minimum external air gap)	Measured from input terminals to output terminals, shortest distance trough air	4	mm
CPG	Creepage (minimum external tracking)	Measured from input terminals to output terminals, shortest distance path along body	4	mm
CTI	Comparative tracking index (tracking resistance)	IEC 60112	≥ 400	V
-	Material group	According to IEC 60664-1	II	-
-	Overvoltage category per IEC 60664-1	Rated mains voltages ≤ 150 V _{RMS}	I - IV	-
		Rated mains voltages ≤ 300 V _{RMS}	I - III	-
		Rated mains voltages ≤ 600 V _{RMS}	I - II	-
		Rated mains voltages ≤ 1000 V _{RMS}	I	-
DIN EN IEC 60747-17 (VDE 0884-17)				
V _{IORM}	Maximum repetitive isolation voltage	AC voltage	1200	V _{PEAK}
V _{IOWM}	Maximum working isolation voltage	AC voltage (sine wave)	849	V _{RMS}
		DC voltage	1200	V _{PEAK}
V _{PR}	Partial discharge test voltage	Method a, type and sample test t _m = 10 s Partial discharge < 5 pC	1920	V _{PEAK}
		Method b1, 100% production test t _m = 1 s Partial discharge < 5 pC	2250	V _{PEAK}
V _{IOTM}	Maximum transient isolation voltage	Method a, type and sample test, t _{ini} = 60 s	4000	V _{PEAK}
V _{IOTM,test}	Transient isolation voltage test	Method b1, 100% production test V _{IOTM,test} = V _{IOTM} × 1.2, t _{ini} = 1 s	4800	V _{PEAK}
V _{IMP}	Maximum impulse voltage	Type test; tested in air 1.2/50 μs waveform per IEC 62368-1	4000	V _{PEAK}
V _{IOSM}	Maximum surge isolation voltage	Type test; tested in oil 1.2/50 μs waveform per IEC 62368-1 V _{IOSM} ≥ V _{IMP} × 1.3	5200	V _{PEAK}
R _{IO}	Isolation resistance	Type test V _{IO} = 500 V; T _{amb} = 25°C	> 10 ¹²	Ω
		Type test V _{IO} = 500 V; T _{amb,max} = 125°C	> 10 ¹¹	
		Type test V _{IO} = 500 V; T _{amb} = T _S = 150°C	> 10 ⁹	
Parameter definitions and test conditions in accordance to IEC 60747-17				

Symbol	Parameter	Test conditions	Value	Unit
UL 1577				
V _{ISO}	Isolation withstand voltage	60 s; type test	2828 / 4000	V _{RMS} /V _{PEAK}
V _{ISO,test}	Isolation voltage test	1 s; 100% production	3394 / 4800	V _{RMS} /V _{PEAK}
Recognized under the UL 1577 component recognition program. File number E362869				

Note: For three-phase systems the values in the tables [Table 7](#) and [Table 8](#), refer to the line-to-neutral voltage.

Table 8. Isolation and safety specification (SO8W package)

Symbol	Parameter	Test conditions	Value	Unit
General				
CLR	Clearance (minimum external air gap)	Measured from input terminals to output terminals, shortest distance trough air	8	mm
CPG	Creepage (minimum external tracking)	Measured from input terminals to output terminals, shortest distance path along body	8	mm
CTI	Comparative tracking index (tracking resistance)	IEC 60112	≥ 400	V
-	Material group	According to IEC 60664-1	II	-
-	Overvoltage category per IEC 60664-1	Rated mains voltages ≤ 150 V _{RMS}	I - IV	-
		Rated mains voltages ≤ 300 V _{RMS}	I - III	-
		Rated mains voltages ≤ 600 V _{RMS}	I - II	-
		Rated mains voltages ≤ 1000 V _{RMS}	I	-
DIN EN IEC 60747-17 (VDE 0884-17)				
V _{IORM}	Maximum repetitive isolation voltage	AC voltage	1500	V _{PEAK}
V _{IOWM}	Maximum working isolation voltage	AC voltage (sine wave)	1060	V _{RMS}
		DC voltage	1500	V _{PEAK}
V _{PR}	Partial discharge test voltage	Method a, type and sample test t _m = 10 s Partial discharge < 5 pC	2400	V _{PEAK}
		Method b1, 100% production test t _m = 1 s Partial discharge < 5 pC	2812	V _{PEAK}
V _{IOTM}	Maximum transient isolation voltage	Method a, type and sample test, t _{ini} = 60 s	5000	V _{PEAK}
V _{IOTM,test}	Transient isolation voltage test	Method b1, 100% production test V _{IOTM,test} = V _{IOTM} × 1.2, t _{ini} = 1 s	6000	V _{PEAK}
V _{IMP}	Maximum impulse voltage	Type test; tested in air 1.2/50 μs waveform per IEC 62368-1	4600	V _{PEAK}
V _{IOSM}	Maximum surge isolation voltage	Type test; tested in oil 1.2/50 μs waveform per IEC 62368-1 V _{IOSM} ≥ V _{IMP} × 1.3	6000	V _{PEAK}
R _{IO}	Isolation resistance	Type and sample test V _{IO} = 500 V; T _{amb} = 25°C	> 10 ¹²	Ω
		Type and sample test V _{IO} = 500 V; T _{amb,max} = 125°C	> 10 ¹¹	
		Type and sample test V _{IO} = 500 V; T _{amb} = T _S = 150°C	> 10 ⁹	
Certified according to IEC 60747-17. Certificate number: 5022192-4880-0002/300335				

Symbol	Parameter	Test conditions	Value	Unit
UL 1577				
V_{ISO}	Isolation withstand voltage	60 s; type test	3540 / 5000	V_{RMS}/V_{PEAK}
$V_{ISO,test}$	Isolation voltage test	1 s; 100% production	4240 / 6000	V_{RMS}/V_{PEAK}
Recognized under the UL 1577 component recognition program. File number E362869				

Table 9. Safety limits

Symbol	Parameter	Test condition	Max	Unit
I_S	Safety input, output, or supply current	$R_{thja}^{(1)} = 115\text{ }^{\circ}\text{C/W}$, $V_i = 5.5\text{ V}$, $t_j = 150^{\circ}\text{C}$, $t_{amb} = 25^{\circ}\text{C}$	197.6	mA
		$R_{thja}^{(1)} = 115\text{ }^{\circ}\text{C/W}$, $V_i = 3.6\text{ V}$, $t_j = 150^{\circ}\text{C}$, $t_{amb} = 25^{\circ}\text{C}$	301.9	
P_S	Safety input, output, or total power	$R_{thja}^{(1)} = 115\text{ }^{\circ}\text{C/W}$, $t_j = 150^{\circ}\text{C}$, $t_{amb} = 25^{\circ}\text{C}$	1087	mW
T_S	Maximum safety temperature		150	$^{\circ}\text{C}$

1. Evaluated on 2 s board in natural convection @ $t_{amb} = 25^{\circ}\text{C}$

Note:

Safety limitings are aimed at minimizing potential damage to the isolation barrier upon failure of input or output circuitry. Without current limiting, excessive power dissipation might damage the die and the isolation barrier consequently. The maximum limits of P_S and I_S should not be exceeded. These limits vary with the ambient temperature T_A , according to the related derating curves

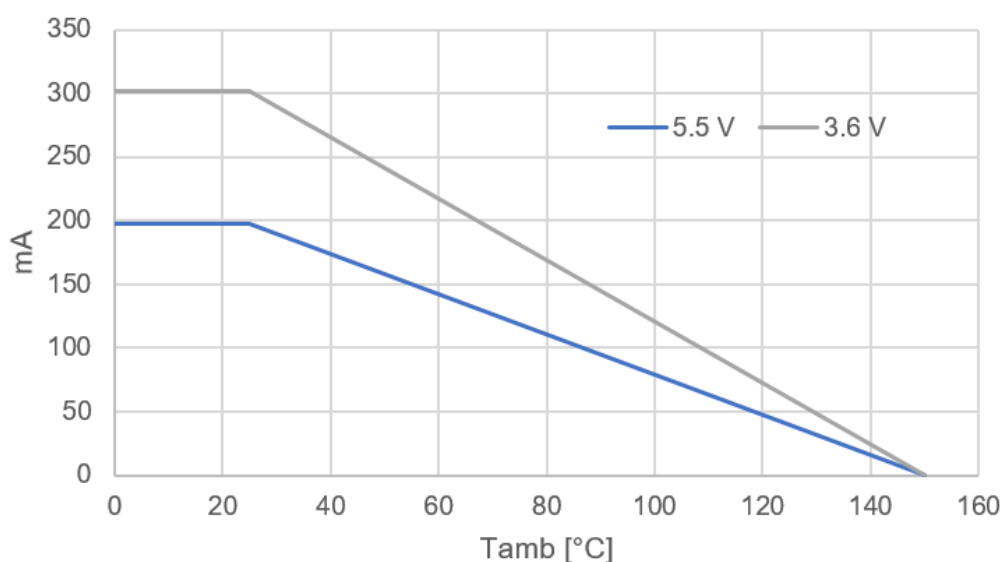
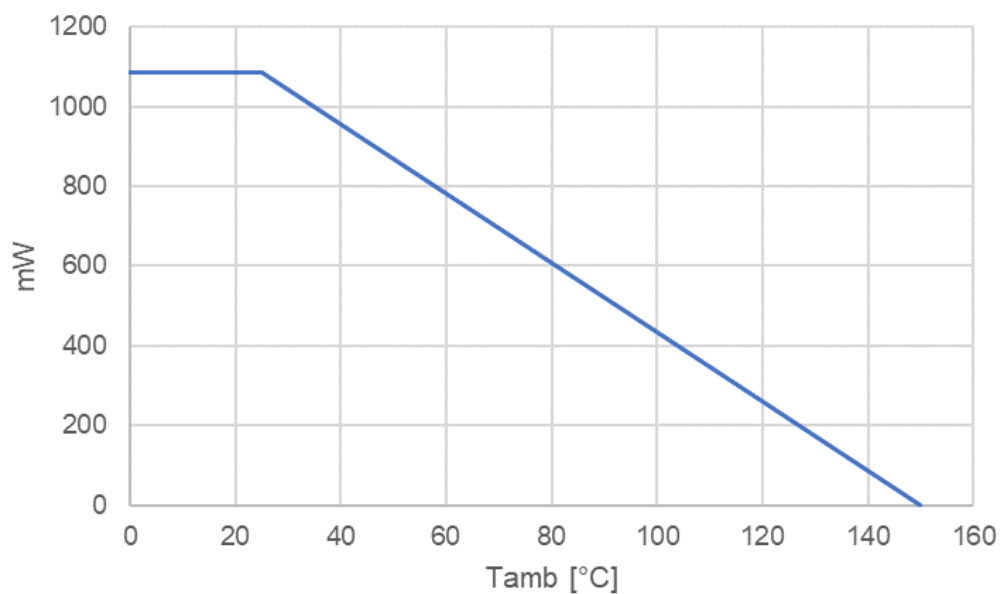
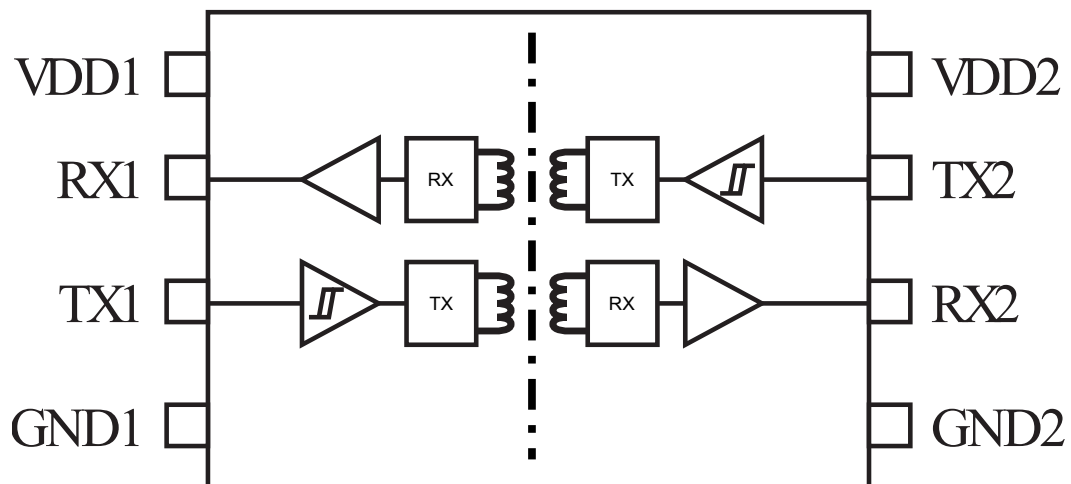
Figure 2. Thermal derating curve for current safety limiting


Figure 3. Thermal derating curve for power safety limiting



5 Pin connection

Figure 4. Pin connection (top view)



6 Pin list

Table 10. Pin description

N.	Name	Type	Function
1	VDD1	Supply	Supply voltage side 1
2	RX1	Logic output	Receive data side 1
3	TX1	Logic input	Transmit data side 1
4	GND1	Ground	Ground side 1
5	GND2	Ground	Ground side 2
6	RX2	Logic output	Receive data side 2
7	TX2	Logic input	Transmit data side 2
8	VDD2	Supply	Supply voltage side 2

7 Device description

The STISO621 is a dual high-speed isolated communication channel. It integrates one channel for each communication direction and provides low levels of pulse width distortion in the full operation range.

7.1 Device operation

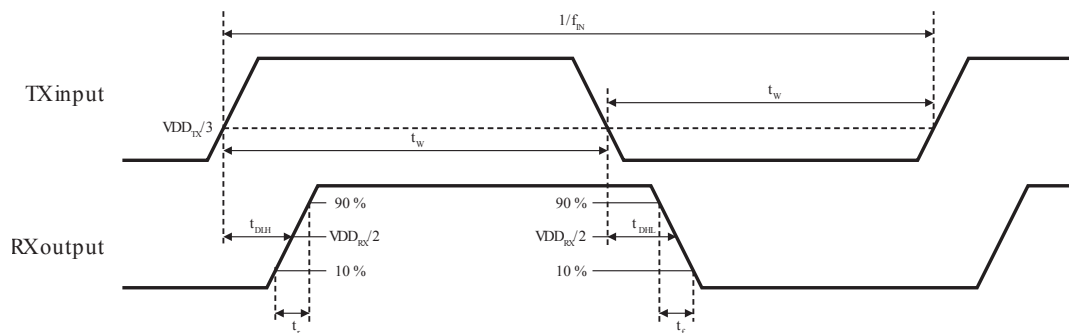
The device operation is described in the following table:

Table 11. Device operation table

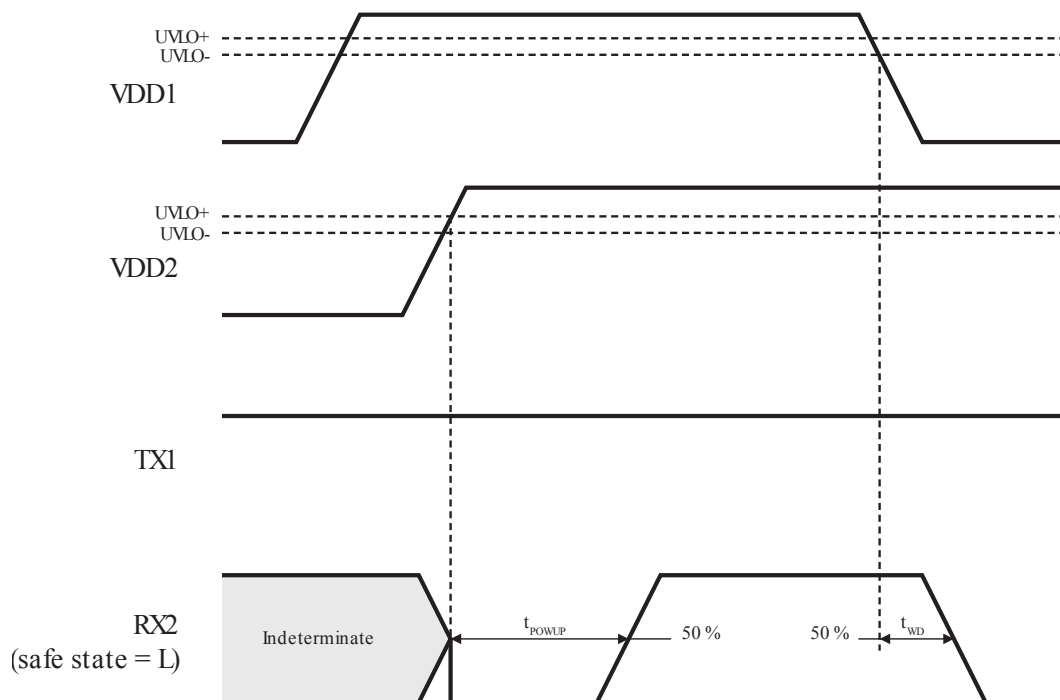
VDD1	VDD2	TX1	RX2	TX2	RX1
Above UVLO	Above UVLO	H	H	H	H
		L	L	H	H
		H	H	L	L
		L	L	L	L
Below UVLO	Above UVLO	X	L ⁽¹⁾	X	Unknown
Above UVLO	Below UVLO	X	Unknown	X	L ⁽¹⁾
Below UVLO	Below UVLO	X	Unknown	X	Unknown

1. A safe state is imposed by default after the watchdog timeout.

Figure 5. Timing diagram



In Figure 5, t_w is the minimum pulse width of the TX pulse, so that the internal logic circuitry doesn't filter the pulse itself. According to the f_{MAX} in Table 4 and Table 5, this value is $t_{w,min} \geq 10ns$.

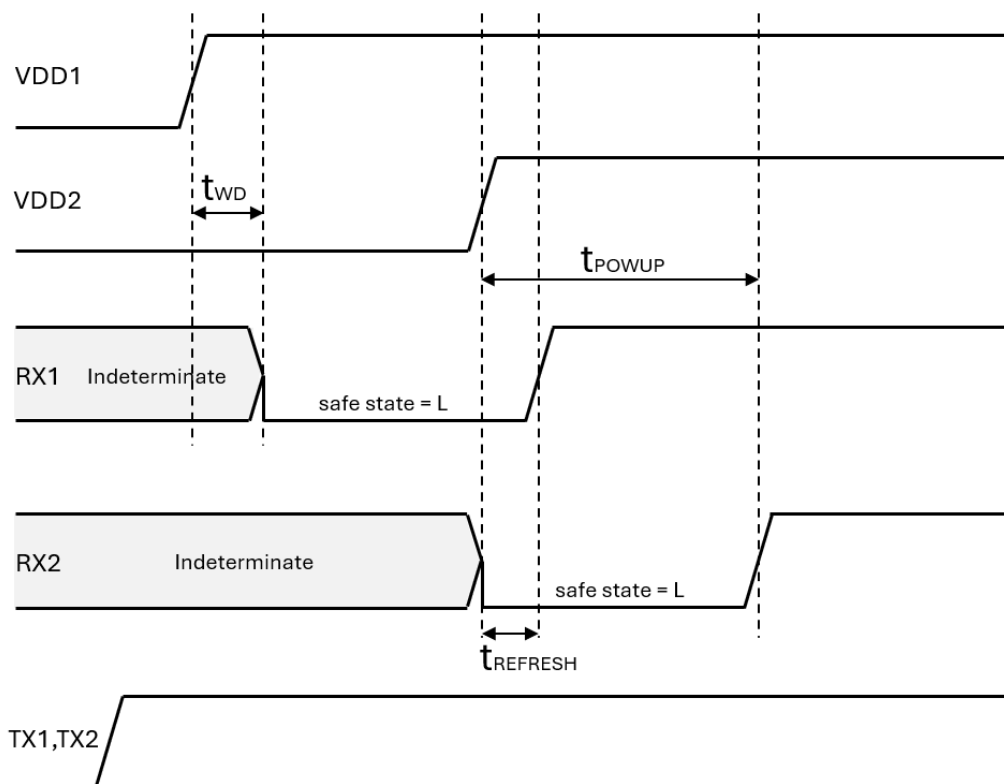
Figure 6. Timing diagram—power up and power down


In Figure 6, t_{POWUP} is the power-up time after that the device is operative as reported in Table 11 when VDD1 and VDD2 are both above the UVLO (normal operation).

7.2 Watchdog and safe state

A watchdog function is present to set the output in a safe state if no data are received from one side to another for a time longer than t_{WD} . A typical application of this function is at the start-up of STISO621. If the supply of one side rises slower than the other one, the output of the faster side is set to the safe state until the other side is in off state. A logic level low is forced as safe state: see Figure 7. Another condition is when the supply of one side is suddenly missing.

Figure 7. Watchdog



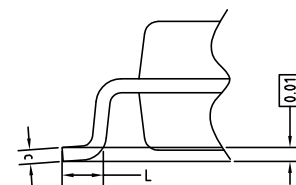
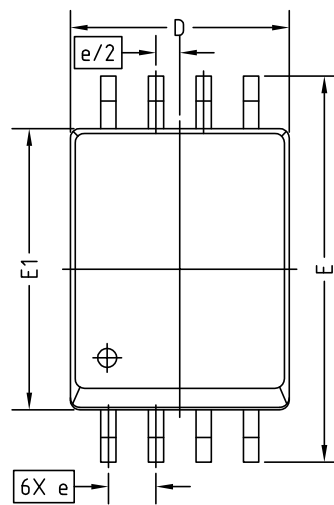
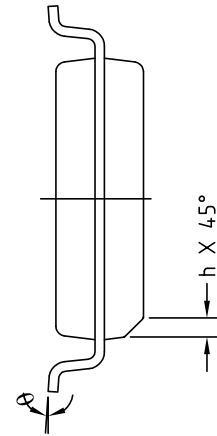
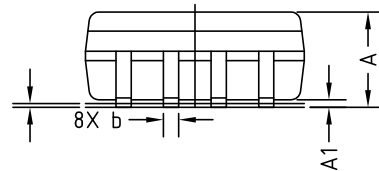
8 Package mechanical data

Table 12. SO8 wide package dimensions

Symbol	Min.	Nom.	Max.	Note
A	2.34		2.64	
A1	0.10		0.30	
b	0.30		0.51	
c	0.20		0.33	
D	5.64		6.05	
e	1.27 BSC			
E1	7.39		7.59	
E	10.11		10.52	
L	0.61		0.91	
h	0.25		0.76	
θ	0°		8°	
aaa		0.25		
bbb		0.25		
ccc		0.10		

Figure 8. SO8 wide package drawings

SIDE VIEW



TOP VIEW

Figure 9. SO8 wide package recommended footprint

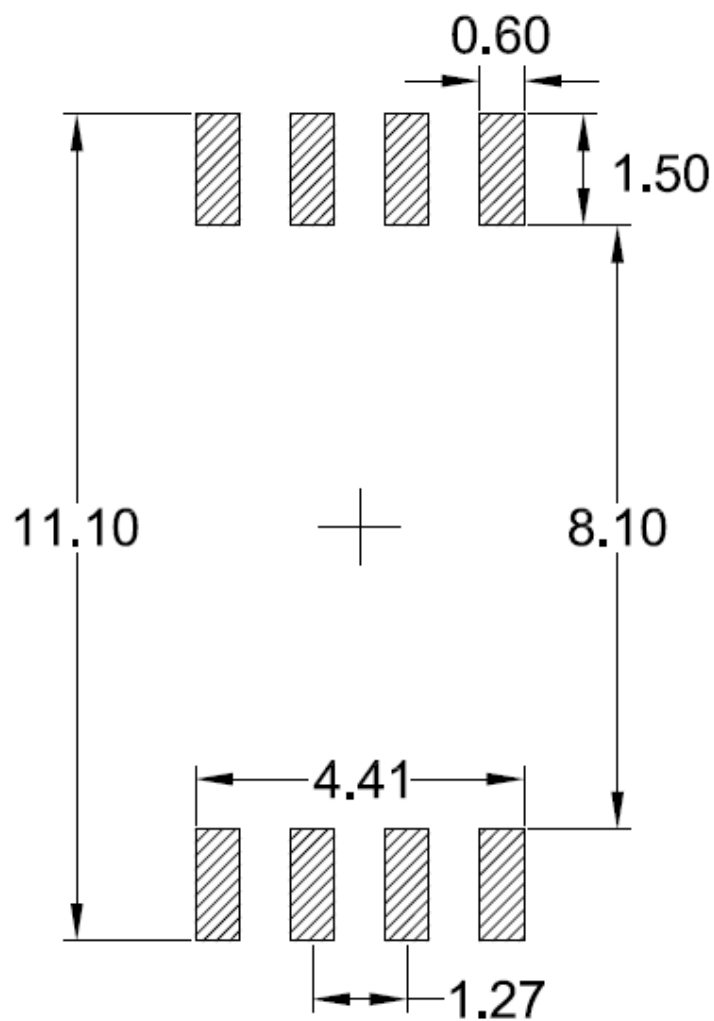
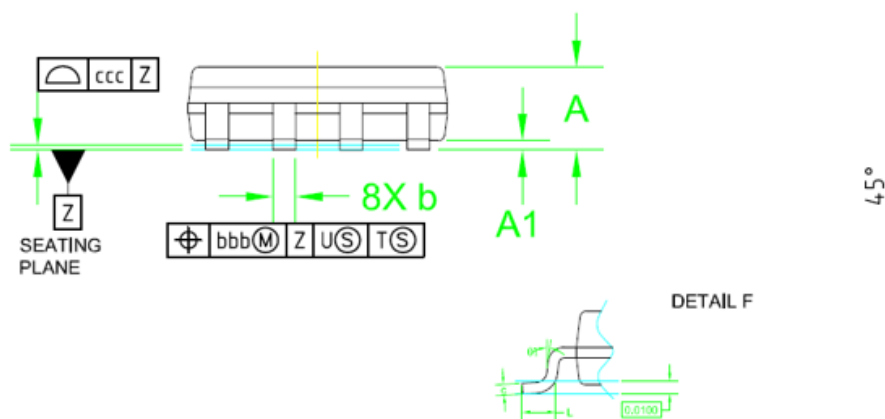


Table 13. SO8 narrow package dimensions

Symbol	Min.	Nom.	Max.
A	1.35		1.75
A1	0.10		0.25
b	0.35		0.49
c	0.19		0.25
D	4.80		5.00
e	1.27BSC		
E1	3.80		4.00
E	5.80		6.20
L	0.40		1.25
h	0.25		0.50
θ	0°		7°
$\Theta 1$	2°		12°
aaa		0.25	
bbb		0.25	
ccc		0.10	

Figure 10. SO8 narrow package drawings

SIDE VIEW



TOP VIEW

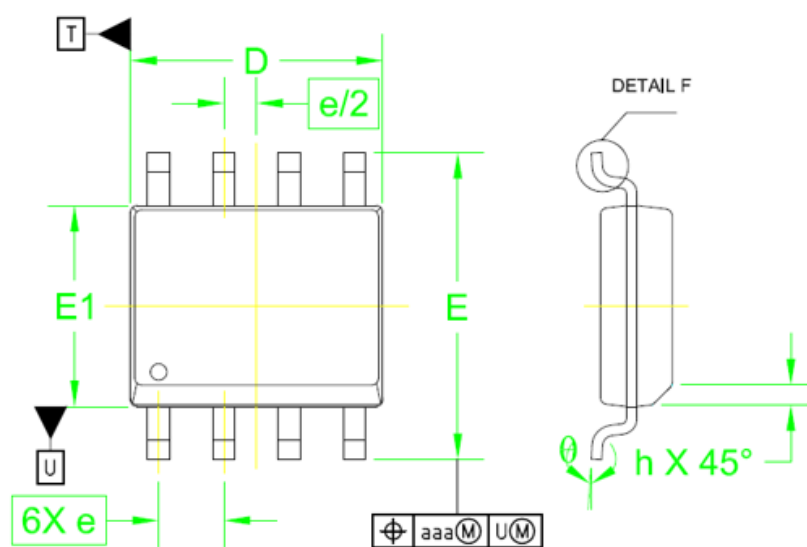
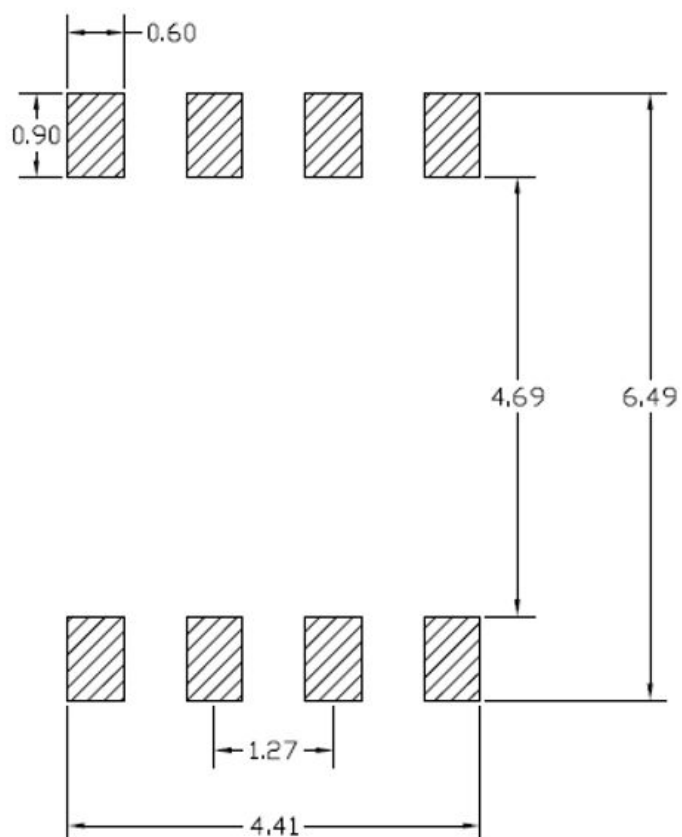


Figure 11. SO8 narrow package recommended footprint



9 Order information

Table 14. Order information

Order code	Package	Packing
STISO621W	S08 wide body	Tube
STISO621WTR	S08 wide body	Tape & reel
STISO621	S08 narrow body	Tube
STISO621TR	S08 narrow body	Tape & reel

Revision history

Table 15. Document revision history

Date	Version	Changes
03-Aug-2020	1	Initial release.
23-Mar-2020	2	SO8 narrow body package option added.
09-May-2022	3	Updated Figure 1 and Figure 4
19-Oct-2022	4	Added UL certification; changed cover image; added STISO621W link.
13-Jan-2025	5	Front page: added reference to IEC 60747-17 certification and isolation ratings values; formatting changes for Table 4 and Table 5 ; in these tables added also a footnote regarding t_{REFRESH} parameter. Added Table 6 with package thermal data. In section 4 Table 7 and Table 8 replaced with new tables each referred to the package version. Added Table 9 with safety limits reported and also Figure 2 , Figure 3 as derating curves. In section 7.1 added a description of parameters t_W in Figure 5 and t_{POWUP} in Figure 6 . Added section 7.2 with Figure 7 . Formatting changes for Table 10 , Table 11 , Table 12 , Table 13 , Table 14 .

Contents

1	Block diagram	2
2	Electrical data	3
2.1	Absolute maximum ratings	3
2.2	Electrical sensitivity	3
2.3	Recommended operating conditions	3
2.4	Electrical characteristics	4
3	Thermal data	6
4	Isolation characteristics	7
5	Pin connection	12
6	Pin list	13
7	Device description	14
7.1	Device operation	14
7.2	Watchdog and safe state	16
8	Package mechanical data	17
9	Order information	23
	Revision history	24
	List of tables	26
	List of figures	27

List of tables

Table 1.	Absolute maximum ratings	3
Table 2.	ESD protection ratings	3
Table 3.	Recommended operating conditions.	3
Table 4.	Electrical characteristics at VDD1 = VDD2 = 5 V	4
Table 5.	Electrical characteristics at VDD1 = VDD2 = 3 V	5
Table 6.	Thermal data.	6
Table 7.	Isolation and safety specification (SO8N package).	7
Table 8.	Isolation and safety specification (SO8W package).	9
Table 9.	Safety limits	10
Table 10.	Pin description.	13
Table 11.	Device operation table	14
Table 12.	SO8 wide package dimensions	17
Table 13.	SO8 narrow package dimensions.	20
Table 14.	Order information	23
Table 15.	Document revision history	24

List of figures

Figure 1.	Block diagram	2
Figure 2.	Thermal derating curve for current safety limiting	10
Figure 3.	Thermal derating curve for power safety limiting	11
Figure 4.	Pin connection (top view)	12
Figure 5.	Timing diagram.	14
Figure 6.	Timing diagram—power up and power down	15
Figure 7.	Watchdog	16
Figure 8.	SO8 wide package drawings	18
Figure 9.	SO8 wide package recommended footprint	19
Figure 10.	SO8 narrow package drawings	21
Figure 11.	SO8 narrow package recommended footprint	22

IMPORTANT NOTICE – READ CAREFULLY

STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, enhancements, modifications, and improvements to ST products and/or to this document at any time without notice. Purchasers should obtain the latest relevant information on ST products before placing orders. ST products are sold pursuant to ST's terms and conditions of sale in place at the time of order acknowledgment.

Purchasers are solely responsible for the choice, selection, and use of ST products and ST assumes no liability for application assistance or the design of purchasers' products.

No license, express or implied, to any intellectual property right is granted by ST herein.

Resale of ST products with provisions different from the information set forth herein shall void any warranty granted by ST for such product.

ST and the ST logo are trademarks of ST. For additional information about ST trademarks, refer to www.st.com/trademarks. All other product or service names are the property of their respective owners.

Information in this document supersedes and replaces information previously supplied in any prior versions of this document.

© 2025 STMicroelectronics – All rights reserved